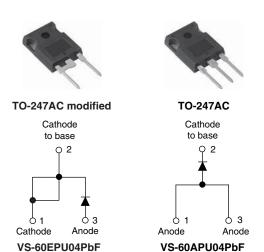


Vishay Semiconductors

Ultrafast Soft Recovery Diode, 60 A FRED Pt®



PRODUCT SUMMARY						
Package	TO-247AC,					
Fackage	TO-247AC modified (2 pins)					
I _{F(AV)}	60 A					
V_{R}	400 V					
V _F at I _F	1.25 V					
t _{rr} typ.	See Recovery table					
T _J max.	175 °C					
Diode variation	Single die					

FEATURES

- · Ultrafast recovery time
- Low forward voltage drop
- 175 °C operating junction temperature
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified for industrial level

BENEFITS

- Reduced RFI and EMI
- · Higher frequency operation
- · Reduced snubbing
- · Reduced parts count

DESCRIPTION/APPLICATIONS

These diodes are optimized to reduce losses and EMI/RFI in high frequency power conditioning systems.

The softness of the recovery eliminates the need for a snubber in most applications. These devices are ideally suited for HF welding, power converters and other applications where switching losses are not significant portion of the total losses.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Cathode to anode voltage	V _R		400	V			
Continuous forward current	I _{F(AV)}	T _C = 127 °C	60				
Single pulse forward current	I _{FSM}	T _C = 25 °C	600	Α			
Maximum repetitive forward current	I _{FRM}	Square wave, 20 kHz	120				
Operating junction and storage temperatures	T_J, T_{Stg}		- 55 to 175	°C			

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS MIN. TYP. MAX.					
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	400	-	-		
Forward voltage		I _F = 60 A	-	1.05	1.25	V	
	V_{F}	I _F = 60 A, T _J = 175 °C	-	0.87	1.03		
		I _F = 60 A, T _J = 125 °C	-	0.93	1.10		
Poverse leakage current		$V_R = V_R$ rated	-	-	50	μΑ	
Reverse leakage current	I _R	$T_J = 150 ^{\circ}\text{C}, V_R = V_R \text{ rated}$	$^{\circ}$ C, $V_{R} = V_{R}$ rated	-	2	mA	
Junction capacitance	C _T	V _R = 400 V	-	50	-	pF	
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	3.5	-	nΗ	

VS-60EPU04PbF, VS-60APU04PbF

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DYNAMIC RECOVERY CHARACTERISTICS (T _C = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS	
		$I_F = 1 A, dI_F/dt = 20$	00 A/μs, V _R = 30 V	-	50	60		
Reverse recovery time	t _{rr}	T _J = 25 °C		-	85	-	ns	
		T _J = 125 °C		-	145	-		
Peak recovery current		T _J = 25 °C	$I_F = 60 \text{ A}$	-	8.8	-	Α	
	IRRM	T _J = 125 °C	$dI_F/dt = 200 \text{ A/}\mu\text{s}$ $V_R = 200 \text{ V}$	=	15.4	-	^	
Reverse recovery charge		T _J = 25 °C		=	375	-	" C	
	Q _{rr}	T _J = 125 °C		-	1120	-	nC	

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Thermal resistance, junction to case	R _{thJC}		-	-	0.70	K/W		
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.2	-	FV VV		
Weight			-	5.5	-	g		
Weight			-	0.2	-	OZ.		
Mounting torque			1.2 (10)	-	2.4 (20)	N · m (lbf · in)		
Madring davise		Case style TO-247AC modified		60EPU04				
Marking device		Case style TO-247AC		60AI	PU04			



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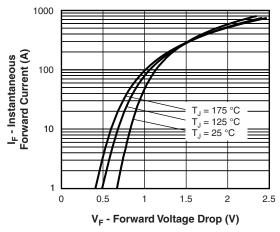


Fig. 1 - Typical Forward Voltage Drop Characteristics

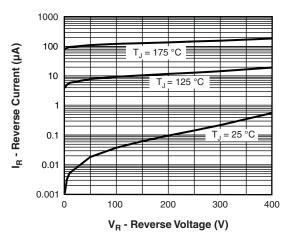


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

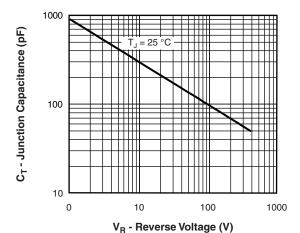


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

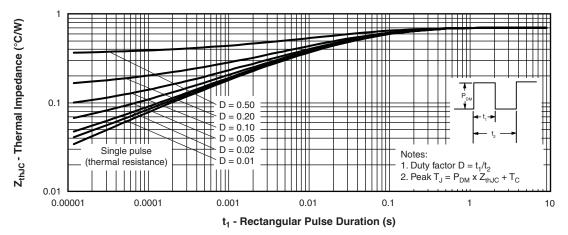


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

VS-60EPU04PbF, VS-60APU04PbF

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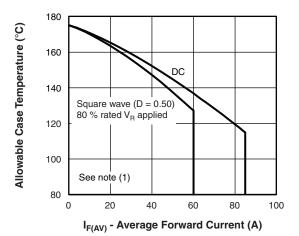


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

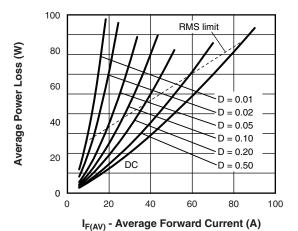


Fig. 6 - Forward Power Loss Characteristics

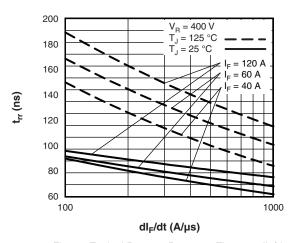


Fig. 7 - Typical Reverse Recovery Time vs. dI_F/dt

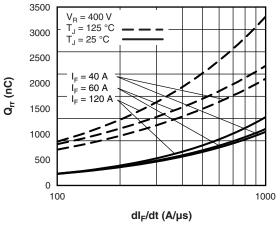


Fig. 8 - Typical Stored Charge vs. dl_F/dt

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Note

 $^{(1)}$ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{th,JC};$ $Pd = Forward power loss = I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = Inverse power loss = V_{R1} \times I_R$ (1 - D); I_R at $V_{R1} = 80~\%$ rated V_R



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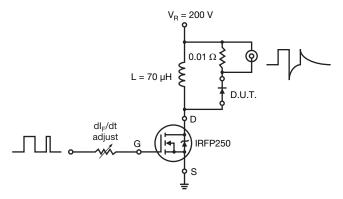
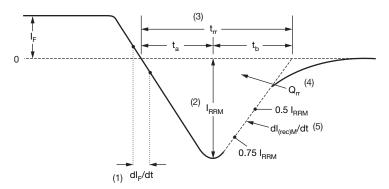


Fig. 9 - Reverse Recovery Parameter Test Circuit



- (1) dl_F/dt rate of change of current through zero crossing
- (2) ${\rm I}_{\rm RRM}$ peak reverse recovery current
- (3) $\rm t_{rr}$ reverse recovery time measured from zero crossing point of negative going $\rm I_F$ to point where a line passing through 0.75 $\rm I_{RRM}$ and 0.50 $\rm I_{RRM}$ extrapolated to zero current.
- (4) $\rm Q_{rr}$ area under curve defined by $\rm t_{rr}$ and $\rm I_{RRM}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) $dI_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}

Fig. 10 - Reverse Recovery Waveform and Definitions

VS-60EPU04PbF, VS-60APU04PbF

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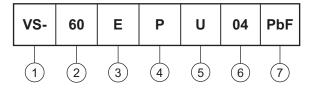


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ORDERING INFORMATION TABLE

Device code



- 1 Vishay Semiconductors product
- 2 Current rating (60 = 60 A)
- 3 Circuit configuration:
 - E = Single diode
 - A = Single diode, 3 pins
- 4 Package:
 - P = TO-247AC (modified)
- 5 Type of silicon:
 - U = Ultrafast recovery
- 6 Voltage rating (04 = 400 V)
- 7 PbF = Lead (Pb)-free

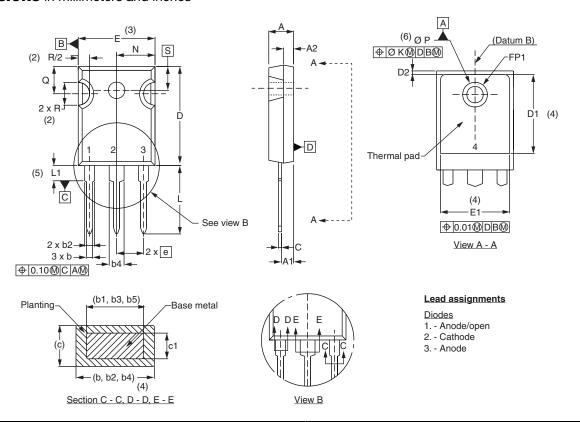
Tube standard pack quantity: 25 pieces

LINKS TO RELATED DOCUMENTS						
Dimensions	TO-247AC modified	www.vishay.com/doc?95253				
Dimensions	TO-247AC	www.vishay.com/doc?95223				
Part marking information	TO-247AC modified	www.vishay.com/doc?95255				
Fait marking information	TO-247AC	www.vishay.com/doc?95226				



Vishay Semiconductors

DIMENSIONS in millimeters and inches



SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.37	0.065	0.094	
b4	2.59	3.43	0.102	0.135	
b5	2.59	3.38	0.102	0.133	
С	0.38	0.86	0.015	0.034	
c1	0.38	0.76	0.015	0.030	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	0.51	1.30	0.020	0.051	
E	15.29	15.87	0.602	0.625	3
E1	13.72	-	0.540	-	
е	5.46	BSC	0.215	BSC	
FK	2.	54	0.010		
L	14.20	16.10	0.559	0.634	
L1	3.71	4.29	0.146	0.169	
N	7.62 BSC		0	.3	
ΦР	3.56	3.66	0.14	0.144	
ФР1	1	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	1.78	0.216	
S	5.51	BSC	0.217 BSC		

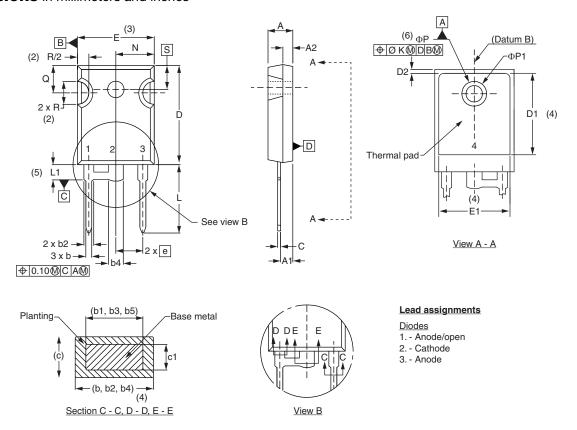
Notes

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC outline TO-247 with exception of dimension c



Vishay Semiconductors

DIMENSIONS in millimeters and inches



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